

HMC322ALP4E

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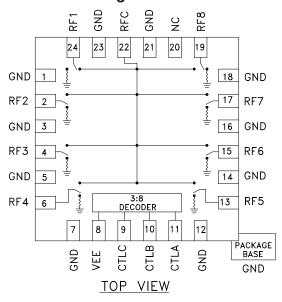
GAAS MMIC SP8T NON-REFLECTIVE SWITCH, DC - 8 GHz

Typical Applications

This switch is suitable for usage in DC - 8.0 GHz 50-Ohm or 75-Ohm systems:

- Broadband
- Fiber Optics
- Switched Filter Banks
- Wireless below 8 GHz

Functional Diagram



Features

Broadband Performance: DC - 8.0 GHz

High Isolation: >30 dB@ 6 GHz

Low Insertion Loss: 2.4 dB@ 6 GHz

Integrated 3:8 TTL Decoder

24 Lead 4x4mm QFN Package: 9 mm²

General Description

The HMC322ALP4E is a broadband non-reflective GaAs MESFET SP8T switch in a low cost leadless surface mount package. Covering DC to 8 GHz, this switch offers high isolation and low insertion loss. This switch also includes an on board binary decoder circuit which reduces the required logic control lines to three. The switch operates using a negative control voltage of 0/-5 volts, and requires a fixed bias of -5V. This switch is suitable for usage in 50-Ohm or 75-Ohm systems.

Electrical Specifications, $T_A = +25^{\circ}$ C, With 0/-5V Control, 50 Ohm System

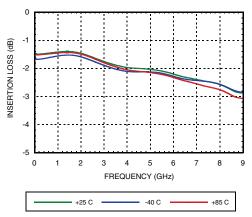
Parameter		Frequency	Min.	Тур.	Max.	Units
Insertion Loss		DC - 2.0 GHz DC - 4.0 GHz DC - 8.0 GHz		1.8 2.0 2.5	2.5 2.7 2.9	dB dB dB
Isolation		DC - 2.0 GHz DC - 4.0 GHz DC - 6.0 GHz DC - 8.0 GHz	35 30 25 20	50 45 40 35		dB dB dB dB
Return Loss	"On State"	DC - 2.0 GHz DC - 8.0 GHz	9 6	17 15		dB dB
Return Loss	"Off State"	DC - 8.0 GHz	7	20		dB
Input Power for 1 dB Compression		0.5 - 8.0 GHz	19	26		dBm
Input Third Order Intercept (Two-Tone Input Power = +7 dBm Each Tone)		0.5 - 8.0 GHz	36	40		dBm
Switching Characteristics tRISE, tFALL (10/90% RF) tON, tOFF (50% CTL to 10/90% RF)		DC - 8.0 GHz		25 150		ns ns



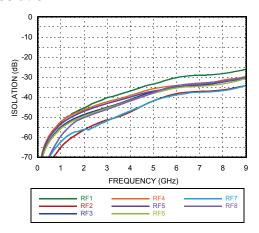
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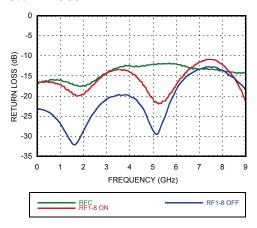
Insertion Loss vs. Temperature



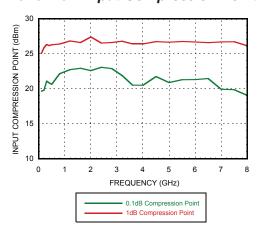
Isolation



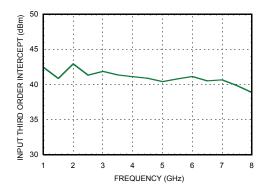
Return Loss



0.1 and 1 dB Input Compression Point



Input Third Order Intercept Point





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Bias Voltage & Current

Vee Range = -5.0 Vdc ± 10%				
Vee (Vdc)	lee (Typ.) (mA)	lee (Max.) (mA)		
-5.0	5.0	9.0		

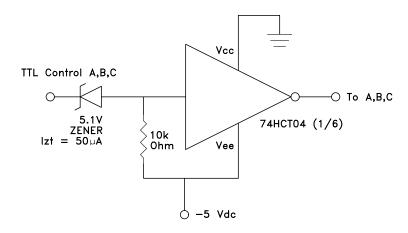
Control Voltages

State	Bias Condition
Low	-3V to 0 Vdc @ 25 μA Typical
High	-5 to -4.2 Vdc @ 5 μA Typical

Truth Table

Control Input		t	Signal Path State	
А	В	С	RFCOM to:	
High	High	High	RF1	
Low	High	High	RF2	
High	Low	High	RF3	
Low	Low	High	RF4	
High	High	Low	RF5	
Low	High	Low	RF6	
High	Low	Low	RF7	
Low	Low	Low	RF8	

TTL Interface Circuit



Note:

Control inputs A, B, and C can be driven directly with TTL logic with -5 Volts applied to the HCT logic gates Vee pin and to Vee (pin 8) of the RF Switch.



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Absolute Maximum Ratings

Bias Voltage Range (Vee)	-7.0 Vdc	
Control Voltage Range (A, B, & C)	Vee -0.5V to +1.0 Vdc	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-40 to +85 °C	
Maximum Input Power		
Insertion Loss Path Terminated Path	26.5 dBm 24 dBm	
Channel Temperature	150 ° C	
Continuous Pdiss (T = 85 ° C) (derate 5.34 mW / ° C)	0.348 W	
Thermal Resistance		
Insertion Loss Path Terminated Path	184 ° C / W 243 ° C / W	
ESD Sensitivity (HBM)	Class 1A	



Outline Drawing

BOTTOM VIEW PIN 24 -.016 [0.40] REF 0.30 .008 [0.20] MIN 19 PIN 1 18 H322A XXXX 13 6 **EXPOSED** LOT NUMBER 2.95 2.65 **GROUND PADDLE SQUARE** 0.05 1. LEADFRAME MATERIAL: COPPER ALLOY 2. DIMENSIONS ARE IN INCHES [MILLIMETERS] SEATING PLANE 3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE. .003[0.08] C 4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM. -c-PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [2]
HMC322ALP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL3 [1]	H322A XXXX

5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.6. ALL GROUND LEADS AND GROUND PADDLE MUST BE

7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED

SOLDERED TO PCB RF GROUND.

LAND PATTERN.

^[1] Max peak reflow temperature of 260 $^{\circ}\text{C}$

^{[2] 4-}Digit lot number XXXX



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Pin Descriptions

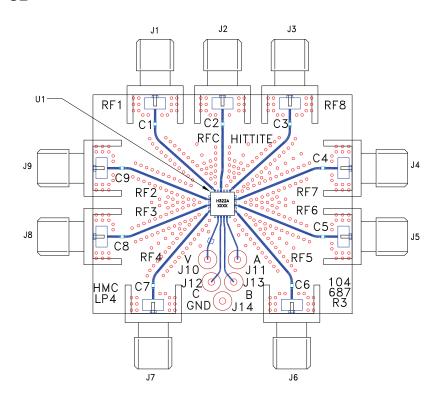
Pin Number	Function	Description	Interface Schematic
1, 3, 5, 7, 12, 14, 16, 18, 21, 23	GND	Package bottom has exposed metal paddle that must also be connected to PCB RF ground.	ĢGND =
2, 4, 6, 13, 15, 17, 19, 22, 24	RF1 - RF8 & RFC	This pin is DC coupled and matched to 50 Ohm. Blocking capacitors are required if RF line potential is not equal to 0V.	
8	VEE	Supply Voltage = -5V ± 10%	VEE 05pF
9	CTLC	See truth table and control voltage table.	<u></u>
10	CTLB	See truth table and control voltage table.	200K
11	CTLA	See truth table and control voltage table.	VEE
20	N/C	This pin should be connected to PCB RF ground to maximize isolation.	



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Evaluation PCB



List of Materials for Evaluation PCB EV1HMC322ALP4 [1]

Item	Description
J1 - J9	PCB Mount SMA RF Connector
J10 - J14	DC Pin
C1 - C9	100 pF Capacitor, 0402 Pkg.
U1	HMC322ALP4E SP8T Switch
PCB [2]	104687 Evaluation PCB 1.73"x1.46"

^[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should be generated with proper RF circuit design techniques. Signal lines at the RF port should have 50 ohm impedance and the package ground leads and backside ground slug should be connected directly to the ground plane similar to that shown above. The evaluation circuit board shown above is available from Analog Devices Inc. upon request.

Mouser Electronics

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Analog Devices Inc.:

HMC322ALP4E HMC322ALP4ETR EV1HMC322ALP4